

Burn-in & Test Socket Workshop

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tttc_{TM}

BITS

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Technical Program

Session 8 Wednesday 3/05/03 10:30AM Properties Of Socket Materials

"Materials For Test Sockets" Richard W. Campbell – Quadrant Engineering Plastic Products

"Permittivity Determination Of Contactor Dielectrics At RF Frequencies" Jason Mroczkowski – Everett Charles Technologies

"High Flow Glass Filled Polyetherimide Resins For Burn-In Test Sockets"

> Ken Rudolph – General Electric Plastics Robert R. Gallucci – General Electric Plastics Chisato Suganuma – General Electric Plastics

Materials For Test Sockets

Richard W. Campbell, Ph.D. Manager of Product Development

Quadrant Engineering Plastic Products Reading, PA USA



Industry Trends / Materials Needs Trends Impact

- Smaller Foot Print
- Smaller Pitch
- Increased
 Functionality
- New Package Designs

- » Higher Insertion Pressure -Stronger Materials
- » Greater Tolerance Control / More Stable
- » More Sensitive to Static Charge / ESd Materials
- Innovative
 Solutions / New
 Materials

Performance Concerns for Materials Used in BiTS

- Mechanical Strength to Withstand Insert Loads
- Thermal Resistance from -55°C to +155°C
- Tight Dimensional Control Over the Full Temperature Range
- Does not Generate Static Charge
- Safely Dissipates Static Electricity

How does an Engineer select the best plastic material(s) for the application?

There are many factors to take into consideration...

Among Selection Factors



- Thermal Environment
- Electrical Requirements
 - Static Dissipation
 - Dielectrics
- Dimensional Stability
 - Thermal
 - Moisture
- Mechanicals
- Longevity in Service
- Availability of Materials
- Ease of Fabrication
- Cost

The Plastics Pyramid



The Material Selection Process

Application Considerations •Bearing & Wear ? •Static/Structural ?

Application

Physical Performance

- Bearing & Wear
- Dimensional Stability
- Strength & Stiffness/
- Electrical

Physical Performance Environment Environmental Considerations • Thermal

- Chemical
- Regulatory

Needs vs. Materials for Bits

		Past	Now	Trend
Performance Characteristics	BiTS Requirements	Vespel SP-1	Torlon 5530	Semitron ESd 520HR
Thermal Stability	-55°C to +155°C	ОК	ОК	ОК
Dimensional Stability	<2.0 x 10 ⁻⁵ in/in/°F	3.0	1.5	1.5
Mechanical Strength (Compression)	Repeated Compressive Loads / Long Life	16 Kpsi	27 Kpsi	30 Kpsi
Static Dissipation (ESd)	10 ¹⁰ – 10 ¹² Ohms / sq	>10 ¹⁴	>10 ¹⁴	10¹⁰ - 10¹²
Low Particulation / No Sloughing	None	N/A	N/A	Non- Sloughing

Mechanical (Strength) Properties

- Wear Resistance or Crush Resistance ??
- Pins and Wires Pressed onto a BiTS Device Are Likely to Compress the Contact Surface More than "Wear" It. Compare Relative Compressive Strengths.
- Maintain Strength at Elevated Temperatures





What About Dimensional Stability?



Coefficient of Linear Thermal Expansion

Celazole PBI Duratron PI Torlon 4203 PAI Torlon 5530 GF PAI Ketron PEEK Ketron GF PEEK Techtron PPS Ryton GF PPS Ultem 1000 Ultem 2300 GF PEI Semitron ESd 420 Semitron ESd 520HR 1.0 2.0 3.0 0.0

x 10⁵ in / in / °F

4.0

There's More to CLTE Than A Single Point

Data Sheets Typically Show A Single Value for CLTE.

The World Is Not That Simple...

There's More to CLTE Than A Single Point



Amorphous Polymers' CLTE



CREEP AT 150C - 1% DEFORMATION

Isometric Stress-Time Curves



Socket Machined from Torlon 4203





Hole Density and Size

 Ever Higher Performance Demands Higher Density / More Complexity

 MPU, Video Graphics
 Approaching 100 µm Hole to Hole Geometries

 BiTS Materials Must Be Able To Deliver

Hole Size and Density Study

- 10 and 5.5 mil holes drilled into 75 mil plates
- Spacing 10, 8, 6, 4 mils wall to wall
- 4 x 4 grid pattern
- Examined by optical microscopy
- Materials:
 - Unfilled Ultem Polyetherimide
 - PEEK Polyetheretherketone
 - GF PEEK (30% GF)
 - Torlon Polyamideimide
 - Torlon 5530 (30% Glass Fibers)
 - Semitron ESd 520HR Static Dissipative Filled Torlon

Machining Conditions Used

- Carbide High Speed Drill Bits

- For 10 Mil Holes:
 - 8,500 RPM
 - 15 inches per minute feed rate
 - 15 mils "peck"
- For 5.5 Mil Holes
 - 10,000 RPM
 - 20-25 inches per minute
 - 20 mils "peck"

PEEK (unfilled)

10 mils @ 5 mils





PEEK (30% Glass Fibers)

10 mils @ 3 mils



Torion 4203 PAI

5.5 mil @ 10 mils



Torlon 4203 PAI.

5.5 mil @ 10 mils



Torlon 4203 (Unfilled)

5.5 mils @ 5 mils





Ultem PEI (unfilled)

5.5 mils x 4 mils



Celazole PBI

10 mils @ 5 mils



Semitron ESd 520HR

10 mils @ 4 mils



Semitron ESd 520HR 5.5 mils @ 10 mils


Torlon 5530 (30% Glass Fiber)

10 mils @ 3 mils



All These Materials Can Be Machined into BiTS Well

- Key: Sharp Bits and Experience
- Unfilled
 - Softer; More difficult to do cleanly
 - But can be done well with technique
- Filled
 - Tendency to machine more cleanly
 - Smaller geometries make it more difficult to get accurate hole to hole spacing
 - Dulls drill bits faster
 - Generates more heat during drilling

Issues in Small Drilling Holes

- Drill Bits are Small and Break Easily
- Bits Dull Quickly, Especially in GF and CF
- GF or CF Can Deflect the Drill Bit
- If There are Several Hundred Holes, Bits Can Break or Dull Well Before Finishing
- Heat, thus CLTE, Can be Issues in High Tolerance Alignment in Unfilled Plastics
- Stress Relief By Supplier and In-Process

CAD Designing is Easy. Making Parts is Tougher

What About Those Static Discharges?



Degrade or Destroy
Semiconductor Devices
⇒ Discharge to the Device
⇒ Discharge from Device
⇒ Field Induced Discharge

 Disruption of an Electronic System Leading to Malfunction or Failure

Electrostatic Dissipative (ESd)

ESd materials are capable of slowly bleeding away static electricity in a controlled manner...

Surface Resistivity (Ω / sq)

10	² 10	D ⁵ 1	0 ¹⁰ 10	12
Conductive	Conductive	Dissipative	High Resistivit	y Insulative
Materials	Range	Range	Range	Range

Engineers specify ESd performance based on the application and the sensitivity of the product to ESD

Typical Impact of Conductive Reinforcement Loading on Electrical Performance



Reliably Maintaining Resistivity Target in Production Environment is Not Feasible via CF Loading Alone

New Technology Was Developed to "Flatten The Percolation Curve"



New Technology Ensures Control and Reliability

Machining or Injection Molding ?

- Large Runs of Same
 Design
- Highest Precision and Closest Tolerances
- Complex Design Freedom
- New Design Evaluation
- Thicker and/or Thinner Cross-sections Possible & Combined
- Lowest Internal Stresses
- No Weld Lines
- Quickest Turn-Around

- » Injection Molding
- » Machining

Extruded or Compression Molded ?

Extruded

- Higher Volume
 Production Runs
- Higher Stresses in Fiber Filled Materials
- Mostly Available to 4" Diameter Rods; to 2" Thick Plate; and 4" OD Tubes
- Longer Lengths (48") for All Geometries

Compression Molded

- Lower Volumes
- Lowest Stress Levels
- Best Dimensional Stability
- Larger Diameter Rods or OD/ID Tubes, but <12" in Length
- Non-Melt
 Processable
 Materials Feasible
- Specialty Formulations Easier to Evaluate





Permittivity Determination of Contactor Dielectrics at RF Frequencies

Jason Mroczkowski Everett Charles Technologies March, 2003



Presentation Topics

- STG's Need
 - To understand contactor material electrical properties in the GHz Frequency Range
- Our Goal
 - Complex permittivity at high frequencies
- The Problem
 - No Published Data at High Frequencies for contactor materials
- Our Solution
 - Measure properties using Vector Network Analyzer
- Some Data
 - Dielectric constant, loss versus frequency
- The Future
- Summary and Conclusion

Our Need

- ECT-STG needed to understand effects of high frequency signals on contactor dielectric materials
 - Increasing operating frequencies of semiconductor devices
 - -10 to 20 times bps needed for bandwidth
 - $-500 \text{ mbps} \rightarrow 5-10 \text{ GHz}$ bandwidth needed
 - **Known:** low frequency properties (MHz)
 - **> Unknown:** high frequency properties (GHz)
 - do properties diverge from low frequency values?
 - If properties do not match published values at High frequencies transmission characteristics will change
 - designed in MHz used at GHz may lead to disaster

The Problem

There is little published data for test contactor material permittivity characteristics in the GHz range

 Current publications specify material properties at low frequencies (e.g.10Mhz or so)

Manufacturer material specifications vary



 Determine dielectric properties of contactor materials in the GHz range

Measure permittivity as function of frequency

Use Software simulations to correlate measured data

Do material properties change as frequency increases

Is there a trend as frequency increases?

Will material properties degrade at high frequency?

If so how will it affect transmission characteristics?

Intro To Permittivity

What is permittivity?

> Ability of material to resist alignment of electron

What is complex permittivity?

- Complex number
- Real part relative permittivity
- Imaginary part attenuation constant (loss)

What is relative permittivity?

- Ratio of material permittivity to that of a vacuum
- Dielectric constant

Why is permittivity important?

- Permittivity describes a materials insulating properties
- Affects characteristic impedance of transmission lines

Theory General permittivity > Complex permittivity $\mathcal{E} = \mathcal{E}_o(\mathcal{E}_r' - \mathcal{E}_r'')$ > **Dielectric constant** (capacity to hold charge) \mathcal{E}_r - Free space $\mathcal{E}_r' = 1$ > **Dielectric and conductor loss** (energy dissipation) - Free space $\mathcal{E}_r'' = 0$ > Loss tangent $\tan \delta = \mathcal{E}_r''/\mathcal{E}_r''$

Characteristic impedance
– change in Zo changes ε_r ' may cause mismatch

Measurement (Obstacles)

Equipment costs

> Off the shelf measurement units - mucho denero



> Only measure to 1GHz

Sample Fabrication

> Milling, etching, polishing, assembly

technique dependent

Obstacles (cont...)

Accuracy and precision of technique

- Error introduced by non-idealities
- More sensitive at high frequency
- Frequency range varies dependent upon technique





Time and RedBull(energy)
Fabrication of samples
Measurement tools needed
Measurement setup
Data acquisition
Extraction of properties from data



The Solution

Measurement technique

- Many solution procedures
- Each technique has advantages and disadvantages

Technique	Field	Advantages	Disadvantages	$\Delta \epsilon'_r$	∆tanδ _r
Transmission-line	TEM,TE ₁₀	Broadband	Precision machining of specimen	±2%	±0.01
Cavity	TE ₀₁₁	Very Accurate	Low Loss	±0.5%	±5x10 ⁻⁴
Dielectric Resonator	TM ₁₁₀	Very Accurate	Low Loss	±.05%	±5x10 ⁻⁴
Whispering Gallery	Hybrid	Very Accurate	High Frequency	±1%	±5x10 ⁻⁶
Fabry Perot	TE ₀₁	Very Accurate	Low Loss	±1%	±5x10 ⁻⁵



Fabry Perot



Open Ended Coax







The Solution (Method)

Coplanar Waveguide T-Resonator

- Resonates at odd-quarter wavelengths
- Impedance independent
- Easy to fabricate samples with scrap material
- Can use air-coplanar microwave probes for testing
- Multiple resonances allow broadband frequency range
- Scalable
- > known equations for ε_{eff} and α_t
- Cost efficient, simple, accurate





The Solution (Method)

- Laminate .5oz. copper to material samples
- Fabricate CPW tee shape to approximate 50ohm impedance
 - .005" (.127mm) slot machined in with very good results
- Add air bridges to reduce slot line resonance
 - Connect grounds to ensure equal potential
 - Eliminate resonance due to stub transition



The Solution (Methods)

- Extract S-Parameters with Vector Network Analyzer
 HP8510C network analyzer
 - Picoprobe 40A-GSG-1000-DS 1mm pitch probes
 - Probes calibrated using full two port SOLT (Short-Open-Load-Thru) technique
 - > Save S_{21} (transmission) data



The Solution (Theory) T-resonator theory ≥ ε_{eff} = ((n•c)/(4 •L_{stub} •f_n))² α_{tot,n} = 8.686 ((π • n•BW_n)/(4• L_{stub} • f_n)) [dB/length] (n=resonance index, c=speed of light, F_n=resonant frequency, BW_n=local 3dB point frequency)



The Solution (Theory)

Dielectric constant and Loss tangent calculation > \mathcal{E}_{r} ' and \mathcal{E}_{r} '' found by solving elliptic integral $K(k) = \int_{0}^{1} \frac{dx}{\sqrt{(1-x^{2})(1-k^{2}x^{2})}}$

$$\int_{V} (1 - k - k - k) = \frac{1}{2} \int_{V} K(k_{1}) = \frac{1}{2} \int_{V} K(k_{2}) \int_{V} K(k_{1}) = \frac{1}{2} \int_{V} K(k_{1}) = \frac{1}{$$

 $\varepsilon_{eff} = \frac{\varepsilon_{r} - 1.0}{2.0} \frac{K(k_{2}')}{K(k_{2})} \frac{K(k_{1})}{K(k_{1}')} + \frac{\varepsilon_{r} - 1.0}{2.0} \frac{K(k_{2}')}{K(k_{2})} \left[\frac{K(k_{1})}{K(k_{1}')} \right]^{2} \left(\frac{t}{b-a} \right) + \frac{2.0t}{b-a} \frac{K(k_{1})}{K(k_{1}')} + \left[\frac{t}{b-a} \frac{K(k_{1})}{K(k_{1}')} \right]^{2} \left(\frac{t}{b-a} \frac{K(k_{1})}{K(k_{1}')} \right]^{2} \left(\frac{t}{b-a} \frac{K(k_{1})}{K(k_{1}')} \right)^{2} \left(\frac{t}{b-a} \frac{K(k_{1})}{K(k$

Requires too much brain power May cause nervous breakdown if calculated manually



Solution - Theory

 Match measured effective dielectric constant to relative dielectric

Match planar-EM simulation to measured resonance to determine loss tangent





Plot measured insertion loss



Extract resonant frequencies and 3dB points from insertion loss plot

Results

Determine relative dielectric using CPW transmission line software



Plot relative dielectric vs. frequency Compare to published (1MHz) data

Material	Ultem 1000	Torlon 5530	Torlon 4203	Peek 1000	PPS
Published Dielectric constant	3.15	6.3	4.2	3.3	3
and the second					



Plot total attenuation vs. frequency



Results: PEEK - Measured vs. Simulated

Compare Measured and Simulated Results



The Future

Testing procedure

- Reduce uncertainties roughness, dispersion
- Improve fabrication techniques of samples airbridges
- -Test other contactor materials
- -Verify impedance independence test @ 25ohms
- Compare to other measurement techniques
- Increase number of resonant frequencies by building a longer stub in 'Tee' structure – more data points
- Stock up on RedBull and.....

Find theoretical property values by computing elliptical integral

Data

 Use findings to more accurately create matched transmission through contactors at high frequencies

Conclusion

- Verified T-Resonator as method for determination of dielectric constant and loss
- Found material properties of Torlon ®, PEEK, Ultem® and PPS at high frequency
- Found published data diverges from measured material properties at RF frequencies
- Successfully correlated 2D and 3D simulations to measured data
 - Ansoft HFSS (3D simulator) and Ensemble® (2D MoM planar EM simulator)
 - Sonnet® (2D MoM planar EM simulator)

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- Material data from: Phillips 66, GE Plastics, Amoco and Quadrant Engineering Plastic Products. Material names used in this presentation are registered trademarks of their manufacturers





High Flow Glass Filled Polyetherimide Resins for Burn-in Test Sockets

2003 Burn-in and Test Socket Workshop March 2 - 5, 2003



Ken Rudolph Robert Gallucci Chisato Suganuma GE Plastics

Contents

- Test Socket Requirements
- Common BiTS Materials
- BiTS Materials Performance Properties
- ULTEM Resin Grades
- BiTS Trends
- ULTEM EPR Technology
- ULTEM Higher Heat Resins
- ESD Considerations
- Conclusions



Courtesy of Aries Electronics, Inc.
Test Socket Requirements I Critical to Quality

- Heat Performance: -55 to 170°C
- Dimensional Stability:
 - Isotropic Properties, Low CTE
- Flex & Tensile Strength & Stiffness:
 - Reduce twisting during assembly
 - Knit-line Strength, No Brittle failure
- Flame Retardancy: UL 94 V-0



Courtesy of Texas Instruments Incorporated

Test Socket Requirements II Critical to Quality

- Processability: Shrinkage, Regrind, Release
- Thin-wall Molding
- Chemical Resistance to Solvents
- Low Out-gassing, Low Contamination
- Lubricity / Wear Resistance



Courtesy of Yamaichi Electronics

Common BiTS Materials



ULTEM Resin Benefits

- High Temperature Modulus & Creep Resistance
- Flexural Strength & Stiffness
- Knit-line Strength & Elongation
- Resistance to Cleaners / Solvents
- Dimensional Stability, Low CTE
- Thin-Wall Flame Retardancy
- Ionic Purity
- Injection Moldable w/ Low Flash
- Extrudable & Machinable
- Lower Specific Gravity



Polyetherimide



Flex Modulus vs. Temperature



Constant Modulus over BiTS Operating Temps

3/5/2003

Tensile & Flex Strength

Strength to Weight Ratios



Highest Strength to Weight for Resin < \$15 /



Low Isotropic Thermal Expansion

Thin Wall Flame Retardance

UL94 V0 rating of High Performance Polymers



ULTEM Resin Grades ULTEM 1000 Base **Un-reinforced Easy Flow** 1010R **2110R** 10 % GF 2110EPR **Glass Filled** ULTEM® **2210R** 20 % GF PEI **2210EPR** Resin 4001 **Easy Flow** Wear Resistant 20 % GF 4211 6010R **Easy Flow** Copolymer 20 % GF 6210R

BiTS Trends

- Larger Geometries:
 - Full Surfaces, Larger Size
 - Increased Pin Counts
- Tighter Pitch:



Courtesy of Hitachi, Ltd. & Enplas Corp.

- $1.27 \rightarrow 1.0 \rightarrow 0.8 \rightarrow 0.65 \rightarrow 0.5 \text{ mm}$
- Higher Heat Requirements
- Electro-Static Dissipative Materials:
 - 10⁶ −10⁸ ohm-cm²
- Reduced Time for Tool Build & Modifications
- Color Coded Guide Rings

Improved Thin Wall Flow; Material Development

Flow Challenges for PEI Resins

- Amorphous Resins Have Broad Softening Range
- Addition of chopped fiberglass (10-40%) to PEI + Increase Modulus, Strength, HDT, FR
 Decreases Elongation & Melt Flow
- Improved Flow Typically Achieved Through Lower Molecular Weight Polymer or Plasticizers
 - Ductility, Knit-line Strength Sacrificed
 - More Susceptible to Degradation
 - Reduction of Tg & HDT

Existing PEI Flow Limited Use in Tighter Pitch BiTS



ULTEM EPR Technology

 Proprietary High Flow Additive Compatible with Glass Reinforced Polyetherimide (10-40% GF)
+ Flow Enhanced by 30%, Improved Release
+ Tensile & Flexural Strength Maintained
+ HDT, CTE & Thermal Aging Maintained
+ UL94-V0 Rating Maintained at 0.4mm

Properties	ULTEM 1000	ULTEM 2210	ULTEM 2210EPR
HDT @1.8MPa	201	211	209
T Str. Mpa	110	140	138
T Mod. Mpa	3600	6900	6900
% Elong.	7%	4%	3%
Flex Mod Mpa	3600	6900	6900
Flex Str Mpa	166	228	207
N. Izod J/m	53	75	80
% Ash	0%	20%	20%
Sp. Gravity	1.27	1.42	1.39
Melt Flow @337C	9.0	9.0	13.0
UL 94-VD (mm)	0.4	0.4	0.4



KGR - 14

ULTEM EPR Technology



ULTEM 2210EPR Melt Processability: 30% Improvement over ULTEM 2210

ULTEM Higher Heat Resins

- High Heat ULTEM Resin Program
 - 230 °C HDT Capable
 - Optimization of MW & Flow
- Addresses Higher Heat Needs for Electronics Market
 - SMT Connector Technology
 - ULTEM-like Properties
 - More Cost Effective than PAI and PEEK
- Commercializing 3Q 2003
 - Unfilled XH6050 Available
 - 10% GF Available for Sampling





ESD Considerations

Stat-Kon[®]

- Electrostatic Discharges can:
 - Ground to humans causing a shock
 - Destroy ICs; Effect Component Operation
- Stat-Kon Dissipative Additives (10⁶-10⁹)
 - Carbon Powder (10-20%, improves wear)
 - Carbon Fiber (~10%, wear, HDT, warp)
- Performance & Metrics
 - No initial charge; Prevents ESD
 - Insulates against high leakage currents
 - Volume & Surface Resistivity; Static Decay





Conclusions

- ULTEM Resins May Satisfy Many Critical To Quality Requirements for Test Sockets
- Thin Wall Flow Needs Are Addressed by ULTEM EPR Technology – 30% Improvement
- Higher Heat ULTEM Resins Can Provide For Max Use Temperatures up to 230 °C
- Custom Compound Resins Can be Formulated to Address ESD, Wear, Flow and Color Requirements

